

CMDD4448

**SURFACE MOUNT
HIGH SPEED SILICON
SWITCHING DIODE**



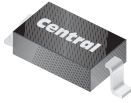
www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMDD4448 type is a ultra-high speed silicon switching diode manufactured by the epitaxial planar process, epoxy molded in a **SUPERmini™** surface mount package, designed for high speed switching applications.

MARKING CODE: 44

SUPERmini™



SOD-323 CASE

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Continuous Reverse Voltage
Peak Repetitive Reverse Voltage
Continuous Forward Current
Peak Repetitive Forward Current
Peak Forward Surge Current, $t_p=1.0\mu\text{s}$
Peak Forward Surge Current, $t_p=1.0\text{s}$
Power Dissipation
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL

V_R 75
 V_{RRM} 100
 I_F 250
 I_{FRM} 500
 I_{FSM} 4.0
 I_{FSM} 1.0
 P_D 275
 T_J, T_{stg} -65 to +175
 Θ_{JA} 545

UNITS

V
V
mA
mA
A
A
mW
 $^\circ\text{C}$
 $^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

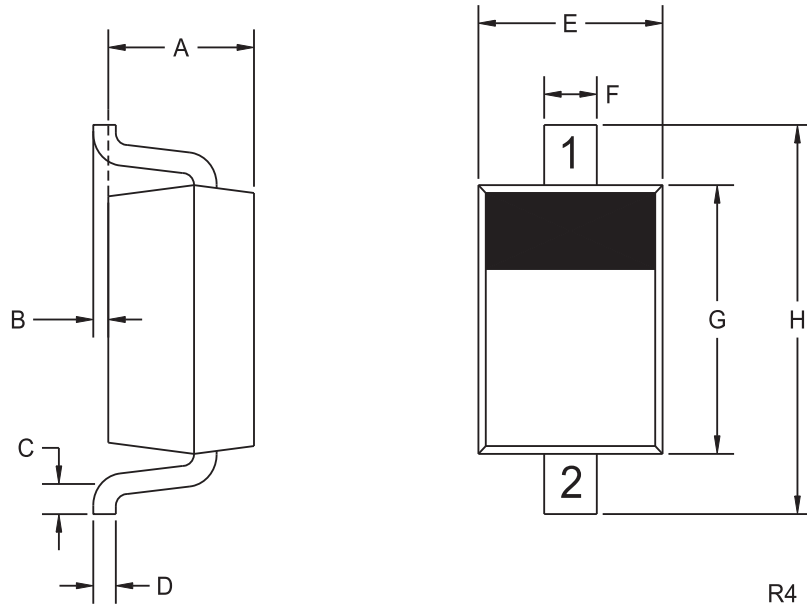
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_R	$V_R=20\text{V}$		25	nA
BV_R	$I_R=5.0\mu\text{A}$	75		V
BV_R	$I_R=100\mu\text{A}$	100		V
V_F	$I_F=5.0\text{mA}$	0.62	0.72	V
V_F	$I_F=100\text{mA}$		1.0	V
C_T	$V_R=0, f=1.0\text{MHz}$		4.0	pF
t_{rr}	$I_R=I_F=10\text{mA}, R_L=100\Omega, \text{Rec. to } 1.0\text{mA}$		4.0	ns

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SOD-323 CASE - MECHANICAL OUTLINE



R4

LEAD CODE:

- 1) CATHODE
- 2) ANODE

MARKING CODE: 44

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.031	0.039	0.80	1.00
B	0.000	0.004	0.00	0.10
C	0.008	-	0.20	-
D	0.004	0.007	0.11	0.19
E	0.045	0.053	1.15	1.35
F	-	0.014	-	0.35
G	0.063	0.071	1.60	1.80
H	0.094	0.102	2.40	2.60

SOD-323 (REV: R4)

R6 (8-January 2010)